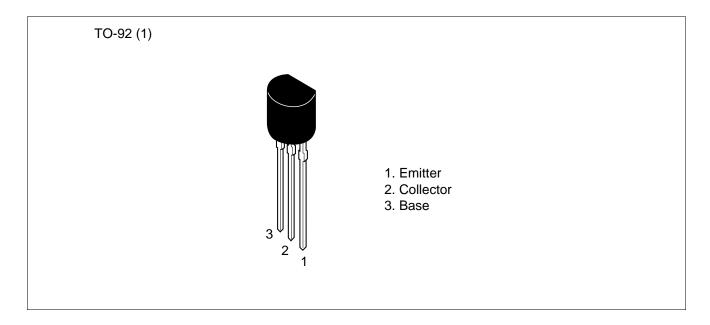
Silicon PNP Epitaxial

# **HITACHI**

### Application

- Low frequency low noise amplifier
- Complementary pair with 2SC2855 and 2SC2856

#### **Outline**



### **Absolute Maximum Ratings** (Ta = 25°C)

Item	Symbol	2SA1190	2SA1191	Unit
Collector to base voltage	$V_{\text{CBO}}$	<b>-90</b>	-120	V
Collector to emitter voltage	$V_{\text{CEO}}$	<b>-90</b>	-120	V
Emitter to base voltage	$V_{EBO}$	<b>-</b> 5	<b>–</b> 5	V
Collector current	I <sub>c</sub>	-100	-100	mA
Emitter current	I <sub>E</sub>	100	100	mA
Collector power dissipation	P <sub>c</sub>	400	400	mW
Junction temperature	Tj	150	150	°C
Storage temperature	Tstg	-55 to +150	-55 to +150	°C

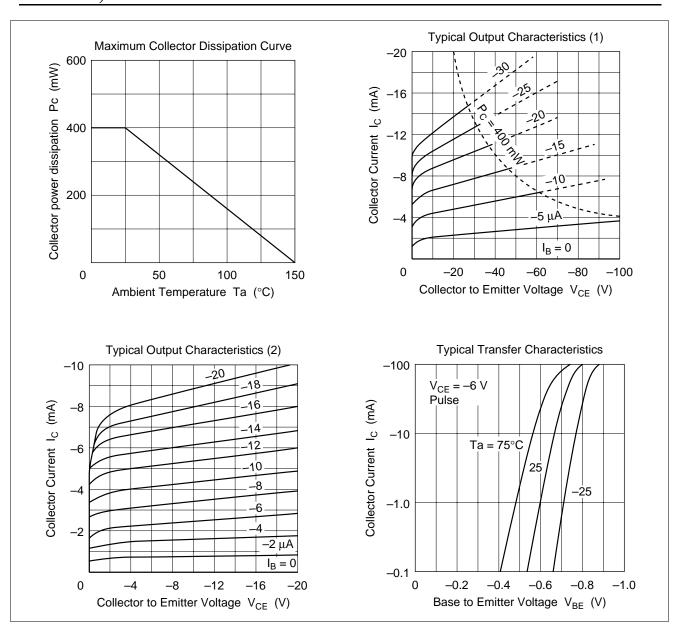
### **Electrical Characteristics** $(Ta = 25^{\circ}C)$

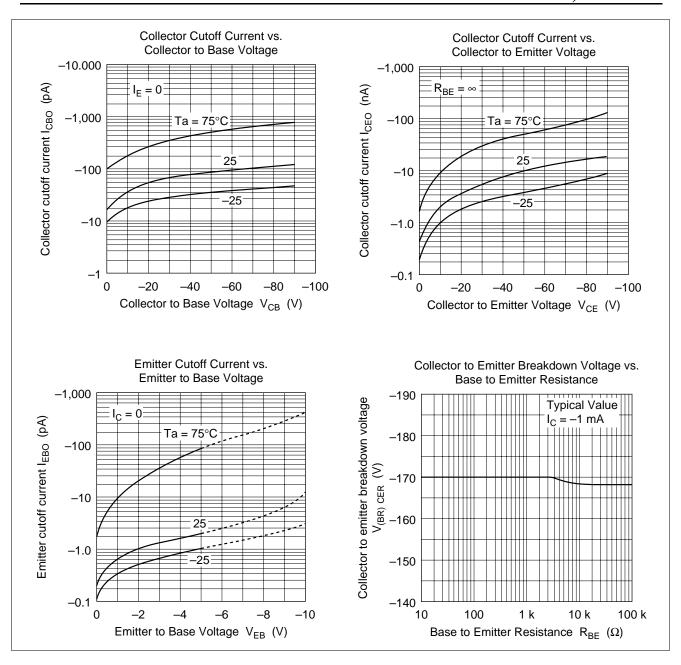
		2SA1	190	00 2SA1191					
Item	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	-90	_	_	-120	_	_	V	$I_{C} = -10 \ \mu\text{A}, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	-90	_	_	-120	_	_	V	$I_{\rm C} = -1$ mA, $R_{\rm BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	<b>-</b> 5	_	_	<b>-</b> 5	_	_	V	$I_{E} = -10 \mu A, I_{C} = 0$
Collector cutoff current	I <sub>CBO</sub>	_	_	-0.1	_	_	-0.1	μΑ	$V_{CB} = -70 \text{ V}, I_{E} = 0$
Emitter cutoff current	I <sub>EBO</sub>	_	_	-0.1	_	_	-0.1	μΑ	$V_{EB} = -2 \text{ V}, I_{C} = 0$
DC current trnsfer ratio	h <sub>FE</sub> *1	250	_	800	250	_	800		$V_{CE} = -12 \text{ V},$ $I_{C} = -2 \text{ mA}^{*2}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	-0.05	-0.15	_	-0.05	-0.15	V	$I_{\rm C} = -10 \text{ mA},$ $I_{\rm B} = -1 \text{ mA}^{*2}$
Base to emitter saturation voltage	$V_{BE(sat)}$	_	-0.7	-1.0	_	-0.7	-1.0	V	_
Gain bandwidth product	f <sub>T</sub>	_	130	_	_	130	_	MHz	$V_{CE} = -6 \text{ V},$ $I_{C} = -10 \text{ mA}$
Collector output capacitance	Cob	_	3.2	_	_	3.2	_	pF	$V_{CB} = -10 \text{ V}, I_{E} = 0,$ f = 1 MHz
Noise figure	NF	_	0.15	1.5	_	0.15	1.5	dB	$V_{CE} = -6 \text{ V},$ $I_{C} = -0.1 \text{ mA},$ $R_{g} = 10 \text{ k}\Omega$ $f = 1 \text{ kHz}$
		_	0.2	2.0	_	0.2	2.0	dB	$V_{CE} = -6 \text{ V},$ $I_{C} = -0.1 \text{ mA},$ $R_{g} = 10 \text{ k}\Omega$ $f = 10 \text{ Hz}$
Noise voltage reffered to input	e <sub>n</sub>	_	0.7	_	_	0.7	_	nV/ √Hz	$V_{CB} = -6 \text{ V},$ $I_{C} = -10 \text{ mA},$ $Rg = 0, f = 1 \text{ kHz}$

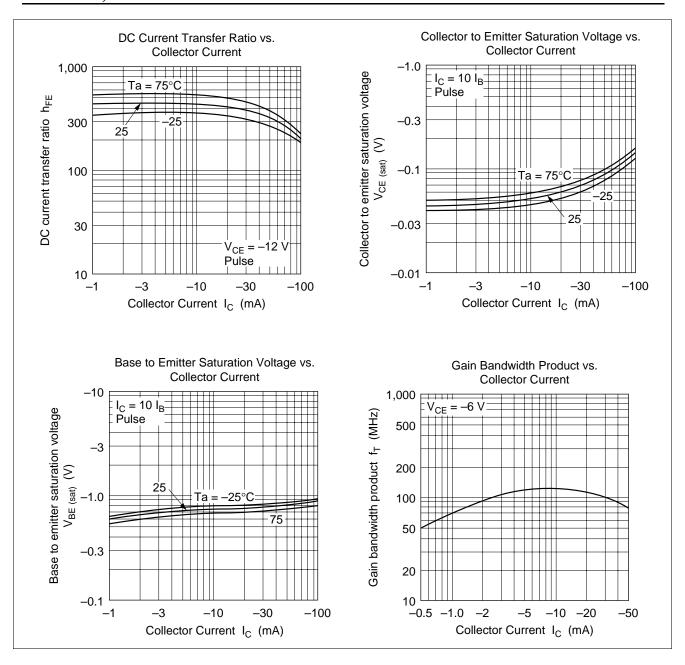
Notes: 1. The 2SA1190 and 2SA1191 are grouped by  $h_{\rm FE}$  as follows.

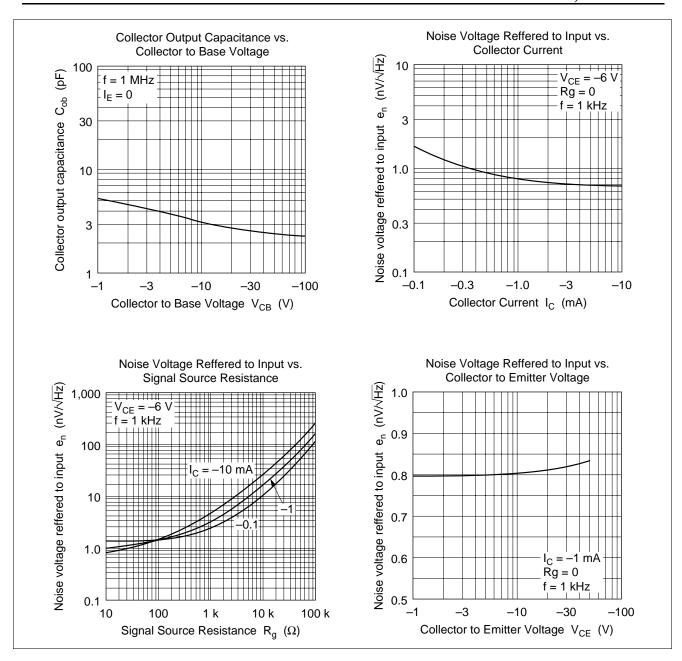
2. Pulse test

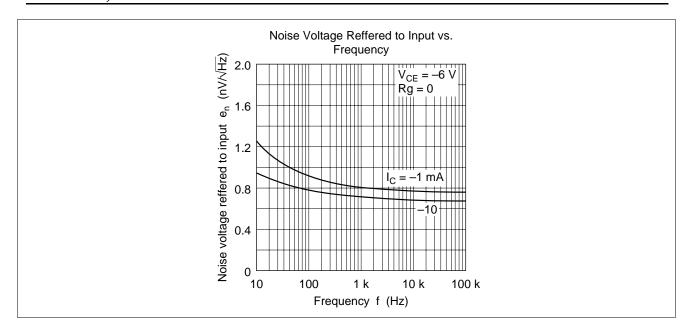
D E 250 to 500 400 to 800



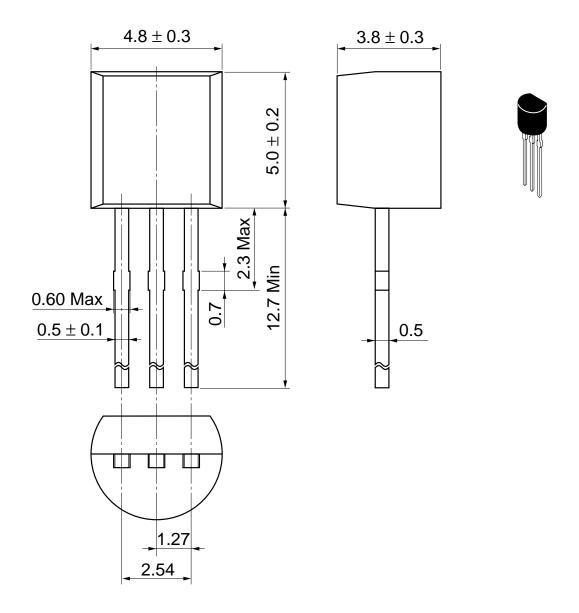








Unit: mm



Hitachi Code	TO-92 (1)
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.25 g

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